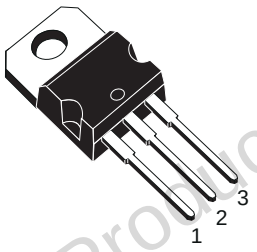
BUL742A

HIGH VOLTAGE FAST-SWITCHING NPN POWER TRANSISTOR

- HIGH VOLTAGE CAPABILITY
- LOW SPREAD OF DYNAMIC PARAMETERS
- MINIMUM LOT-TO-LOT SPREAD FOR RELIABLE OPERATION
- VERY HIGH SWITCHING SPEED



TO-220

APPLICATIONS

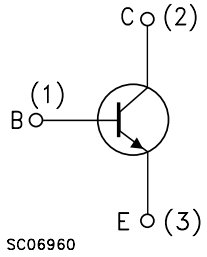
- FOUR LAMP ELECTRONIC BALLAST FOR:
  120 V MAINS IN PUSH-PULL CONFIGURATION;
  277 V MAINS IN HALF BRIDGE CURRENT FEED CONFIGURATION.
- SWITCH MODE POWER SUPPLIES

DESCRIPTION

The BUL742A is manufactured using high voltage Multi Epitaxial Planar technology for high switching speeds and high voltage capability.

Thanks to an increased intermediate layer, it has an intrinsic ruggedness which enables the transistor to withstand an high collector current level during breakdown condition, without using the transil protection usually necessary in typical converters for lamp ballast.

INTERNAL SCHEMATIC DIAGRAM



ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
V_{CES}	Collector-Emitter Voltage (V_{BE} = 0)	950	V
V_{CEO}	Collector-Emitter Voltage (I_B = 0)	400	V
V_{EBO}	Emitter-Base Voltage (I_C = 0, $I_B \leq 2$ A, $t_p < 10\mu s$, $T_j < 150^oC$)	$V_{(BR)EBO}$	V
I_C	Collector Current	4	A
I_{CM}	Collector Peak Current (t_p <5 ms)	8	A
I_B	Base Current	2	A
I_{BM}	Base Peak Current (t_p <5 ms)	4	A
P_{tot}	Total Dissipation at Tc = 25 ^oC	70	W
T_{stg}	Storage Temperature	-65 to 150	^oC
T_j	Max. Operating Junction Temperature	150	^oC

THERMAL DATA

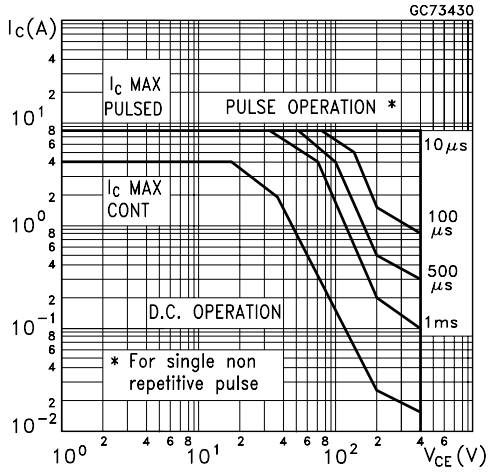
$R_{thj\text{-}case}$	Thermal Resistance Junction-Case	Max	1.78	°C/W
$R_{thj\text{-}amb}$	Thermal Resistance Junction-Ambient	Max	62.5	°C/W

ELECTRICAL CHARACTERISTICS (T_{case} = 25 °C unless otherwise specified)

Symbol	Parameter	Test Conditions		Min.	Typ.	Max.	Unit
I_{CES}	Collector Cut-off Current (V_{BE} = 0)	V_{CE} = 950 V				100	µA
I_{CEO}	Collector Cut-off Current (I_B = 0)	V_{CE} = 400 V				250	µA
$V_{CEO(sus)}$*	Collector-Emitter Sustaining Voltage (I_B = 0)	I_C = 10 mA	L = 25 mH	400			V
$V_{(BR)EBO}$	Emitter-Base Breakdown Voltage (I_C = 0)	I_E = 1 mA		12		24	V
$V_{CE(sat)}$*	Collector-Emitter Saturation Voltage	I_C = 1 A I_C = 3.5 A	I_B = 0.2 A I_B = 1 A			0.5 1.5	V V
$V_{BE(sat)}$*	Base-Emitter Saturation Voltage	I_C = 3.5 A	I_B = 1 A			1.5	V
h_{FE}*	DC Current Gain	I_C = 800 mA I_C = 10 mA	V_{CE} = 3 V V_{CE} = 5 V	16 10		40	
t_s t_f	RESISTIVE LOAD Storage Time Fall Time	V_{CC} = 250 V I_{B1} = 0.5 A t_p = 30 µs	I_C = 2.5 A I_{B2} = -1 A (see figure 2)		0.9 100		µs ns
E_{sb}	Avalanche Energy	L = 2 mH	(see figure 1)	6			mJ

* Pulsed: Pulse duration = 300 µs, duty cycle 1.5 %

Safe Operating Areas



Derating Curve

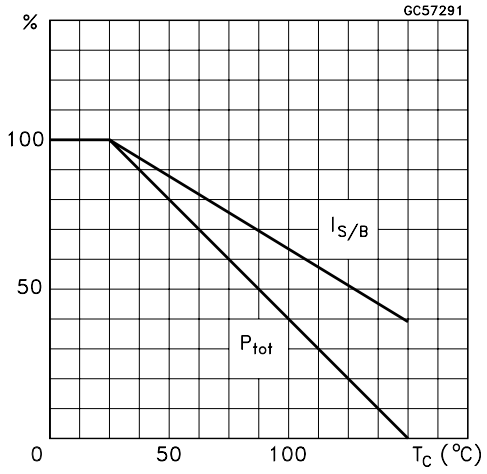


Figure 1: Energy Rating Test Circuit

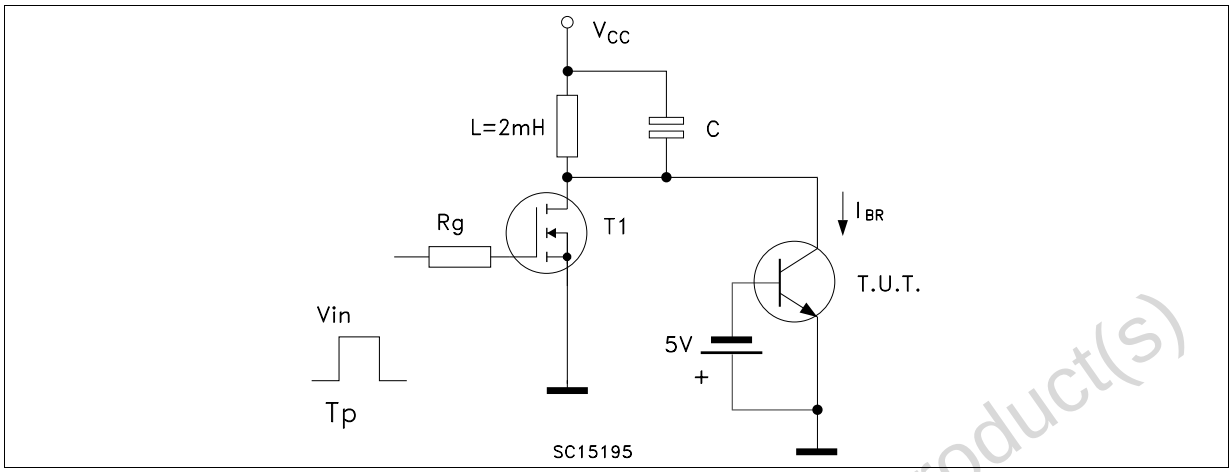
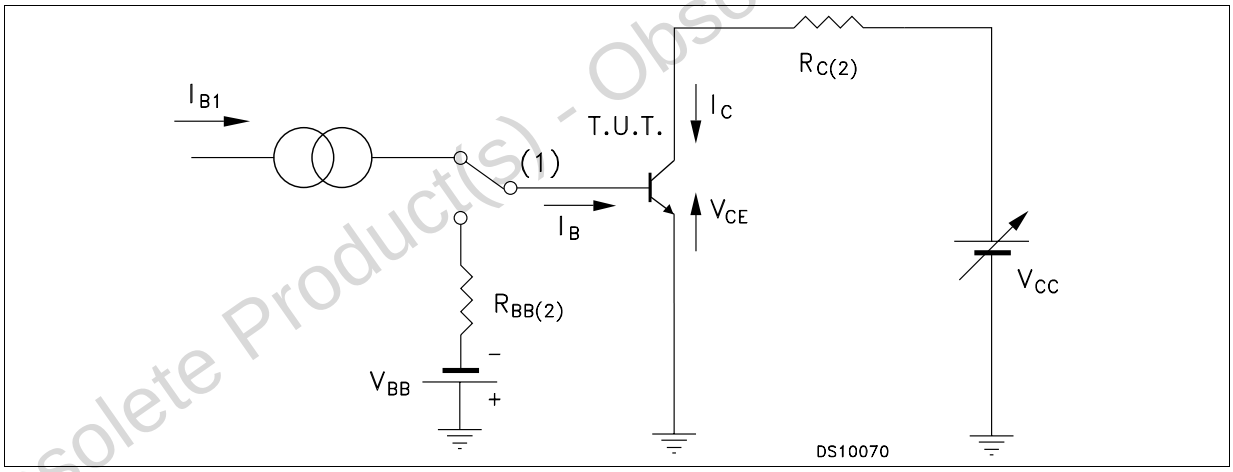
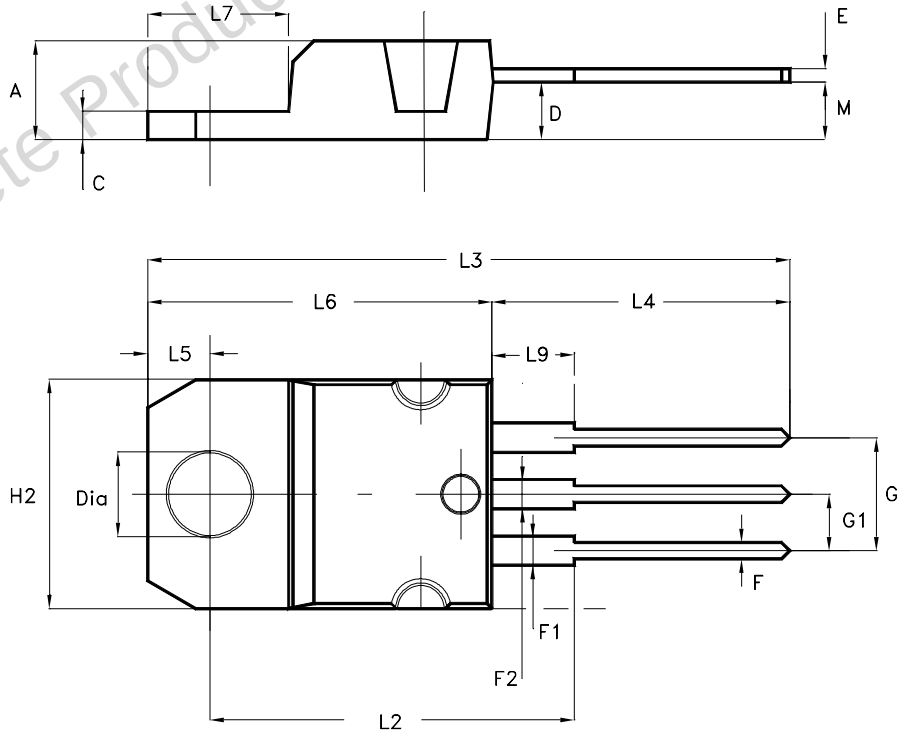


Figure 2: Resistive Load Switching Test Circuit



TO-220 MECHANICAL DATA

DIM.	mm			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
A	4.40		4.60	0.173		0.181
C	1.23		1.32	0.048		0.052
D	2.40		2.72	0.094		0.107
E	0.49		0.70	0.019		0.027
F	0.61		0.88	0.024		0.034
F1	1.14		1.70	0.044		0.067
F2	1.14		1.70	0.044		0.067
G	4.95		5.15	0.194		0.202
G1	2.40		2.70	0.094		0.106
H2	10.00		10.40	0.394		0.409
L2		16.40			0.645	
L4	13.00		14.00	0.511		0.551
L5	2.65		2.95	0.104		0.116
L6	15.25		15.75	0.600		0.620
L7	6.20		6.60	0.244		0.260
L9	3.50		3.93	0.137		0.154
M		2.60			0.102	
DIA.	3.75		3.85	0.147		0.151



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